

ES1A-ES1D

1.0 A Ultra Fast Recovery Rectifier

Features

- For Surface Mount Applications
- Glass Passivated Junction
- Low Profile Package
- Easy Pick and Place
- Built-in Strain Relief
- Superfast Recovery Times for High Efficiency
- This Device is Pb-Free and is RoHS Compliant

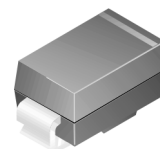
Applications

- This Product is General Usage and Suitable for Many Different Applications



ON Semiconductor®

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SMA
CASE 403AE
(COLOR BAND DENOTES CATHODE)

MARKING DIAGRAM



\$Y	= ON Semiconductor Logo
&Z	= Assembly Plant Code
&3	= Data Code (Year & Week)
ES1X	= Specific Device Code
X	= A/B/C/D

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ES1A-ES1D

ABSOLUTE MAXIMUM RATINGS $T_A = 25^\circ\text{C}$ Unless Otherwise Noted

Symbol	Parameter	Value				Units
		1A	1B	1C	1D	
V_{RRM}	Maximum Repetitive Reverse Voltage	50	100	150	200	V
$I_{F(AV)}$	Average Rectified Forward Current, @ $T_A = 120^\circ\text{C}$	1.0				A
I_{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	30				A
T_{stg}	Storage Temperature Range	-50 to +150				$^\circ\text{C}$
T_{Jm}	Operating Junction Temperature	-50 to +150				$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Units
P_D	Power Dissipation	1.47	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient*	85	$^\circ\text{C/W}$
$R_{\theta JL}$	Thermal Resistance, Junction to Lead*	35	$^\circ\text{C/W}$

*Device mounted on FR-4 PCB 0.013 mm.

ELECTRICAL CHARACTERISTICS $T_J = 25^\circ\text{C}$ Unless Otherwise Noted

Symbol	Parameter	Device				Units
		1A	1B	1C	1D	
V_F	Forward Voltage @ 1.0 A	0.92				V
t_{rr}	Reverse Recovery Time $I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{RR} = 0.25\text{ A}$	15				ns
I_R	Reverse Current @ rated V_R $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	5.0 100				μA
C_T	Total Capacitance $V_R = 4.0\text{ V}$, $f = 1.0\text{ MHz}$	7.0				pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PACKAGE MARKING AND ORDERING INFORMATION TBD

Device Marking	Device	Package	Quantity [†]
ESD1	ESD1	SMA	7500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ES1A-ES1D

TYPICAL CHARACTERISTICS

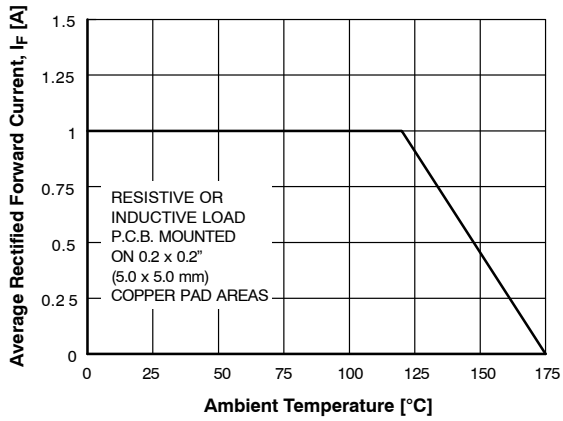


Figure 1. Forward Current Derating Curve

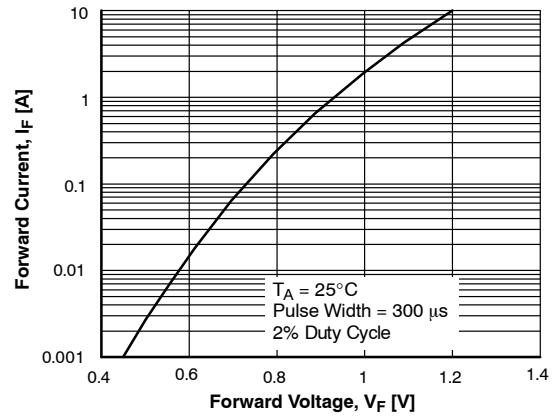


Figure 2. Forward Voltage Characteristics

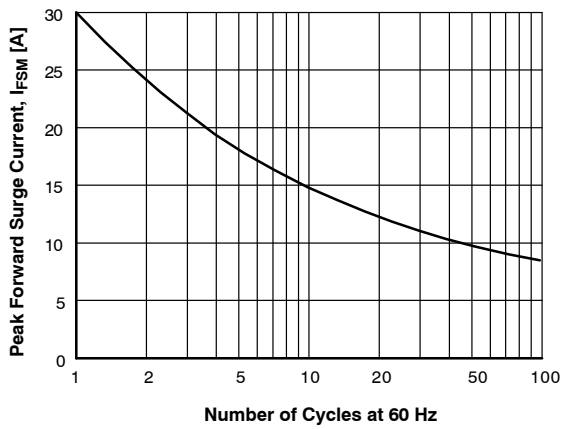


Figure 3. Non-Repetitive Surge Current

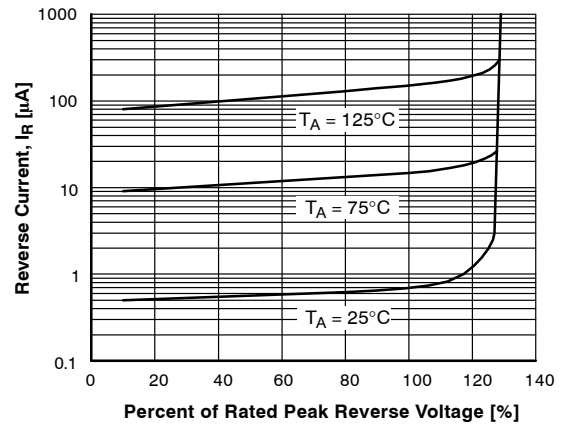


Figure 4. Reverse Current vs Reverse Voltage

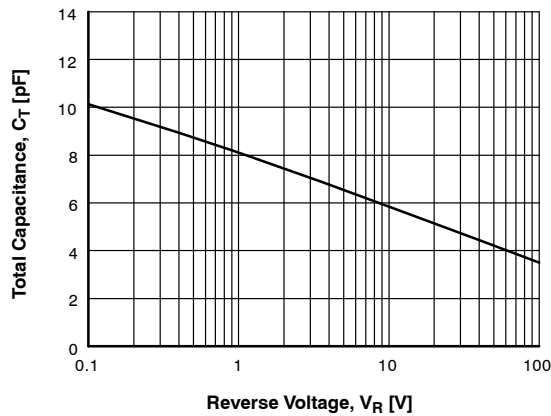
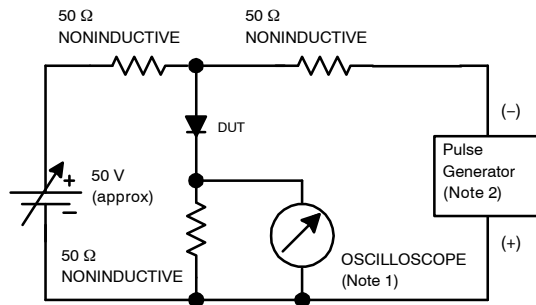


Figure 5. Total Capacitance

TYPICAL CHARACTERISTICS (continued)



NOTES:

1. Rise time = 7.0 ns max; Input impedance = 1.0 MΩ 22 pf.
2. Rise time = 10 ns max; Source impedance = 50 Ω.

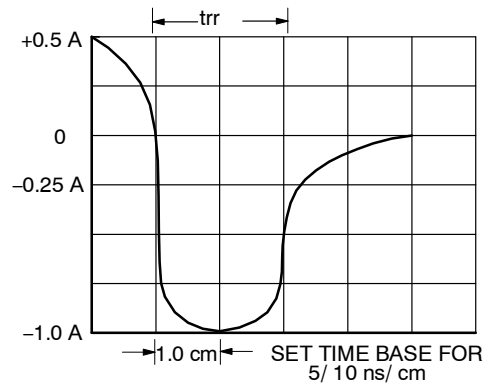
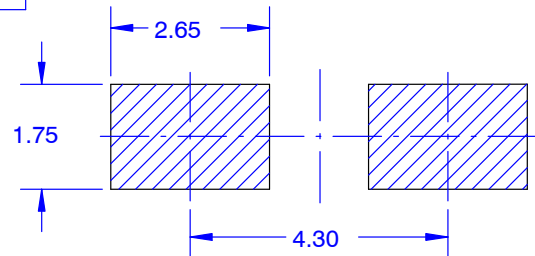
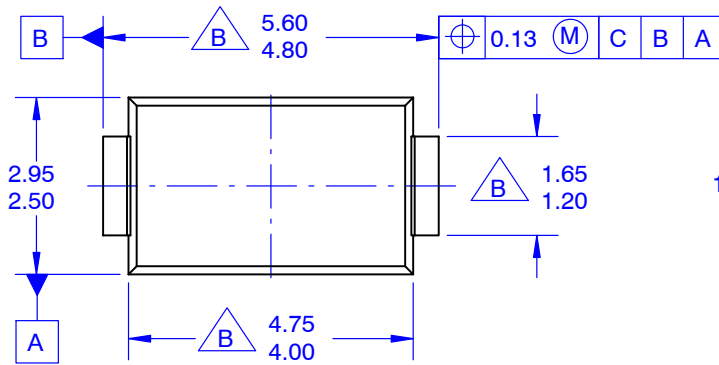


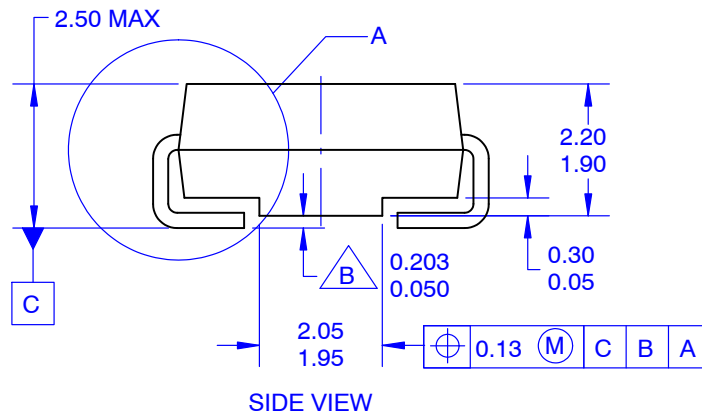
Figure 6. Reverse Recovery Time Characteristic and Test Circuit Diagram

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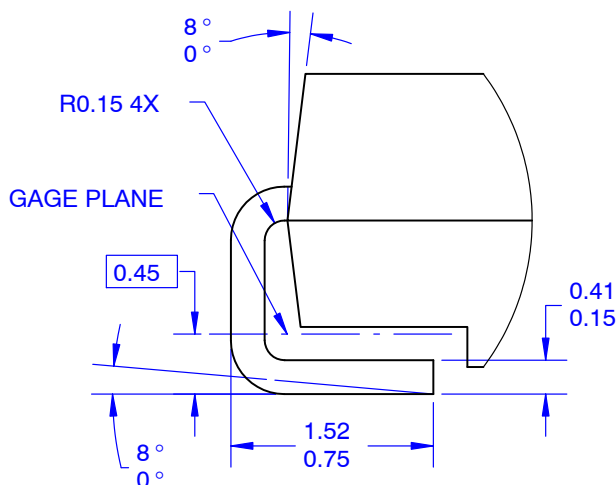


LAND PATTERN RECOMMENDATION



NOTES:

- A. EXCEPT WHERE NOTED, CONFORMS TO JEDEC DO214 VARIATION AC.
- B. DOES NOT COMPLY JEDEC STANDARD VALUE.
- C. ALL DIMENSIONS ARE IN MILLIMETERS.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- E. DIMENSIONS AND TOLERANCE AS PER ASME Y14.5-2009.
- E. LAND PATTERN STD. DIOM5025X231M



DETAIL A
SCALE 20 : 1

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